NSN 5961-01-285-3665

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-285-3665 **Inclosure Material:** Metal **Overall Length:** Between 1.162 inches and 1.253 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Overall Width Across Flats:** Between 0.423 inches and 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 repetitive peak reverse voltage and 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes collector current, dc absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Special Features:** Item described is mounted to plate 4.25 in x 1.0 in x 0.12 in w/ electrical connection to attachment hole. **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No